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February 2007

### Features

**Applications** 

- Floating Channel for Bootstrap Operation to +600V
- Typically 350mA/650mA Sourcing/Sinking Current Driving Capability
- Extended Allowable Negative V<sub>S</sub> Swing to -9.8V for Signal Propagation at V<sub>DD</sub>=V<sub>BS</sub>=15V
- High-Side Output In-Phase of Input Signal
- V<sub>DD</sub> & V<sub>BS</sub> Supply Range from 10V to 20V
- 3.3V and 5V Input Logic Compatible
- Built-in Common Mode dv/dt Noise Canceling Circuit
- Built-in UVLO Functions for Both Channels

Normal Half-Bridge and Full-Bridge Driver

Switching Mode Power Supply

PDP Energy Recovery Switch Control Driver

### Description

The FAN7385 is a monolithic high side gate drive IC designed for high voltage, high speed driving MOSFETs and IGBTs operating up to +600V.

Fairchild's high-voltage process and common-mode noise canceling technique provide stable operation of high-side drivers under high-dv/dt noise circumstances.

An advanced level-shift circuit allows high-side gate driver operation up to  $V_{S}$  = -9.8V (typical) for  $V_{BS}$  = 15V.

The UVLO circuits prevent malfunction when  $V_{BS1}$  and  $V_{BS2}$  are lower than the specified threshold voltage.

Output drivers typically source/sink 350mA/650mA, respectively, which is suitable for dual high-side switches and half-bridge inverters.

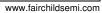
14-SOP

### **Ordering Information**

Part Number	Package	Pb-Free	Operating Temperature Range	Packing Method
FAN7385M <sup>(1)</sup>	(1) (4) 14-SOP Yes		-40°C ~ 125°C	Tube
FAN7385MX <sup>(1)</sup>	14-30F	165	-40 0 - 125 0	Tape & Reel

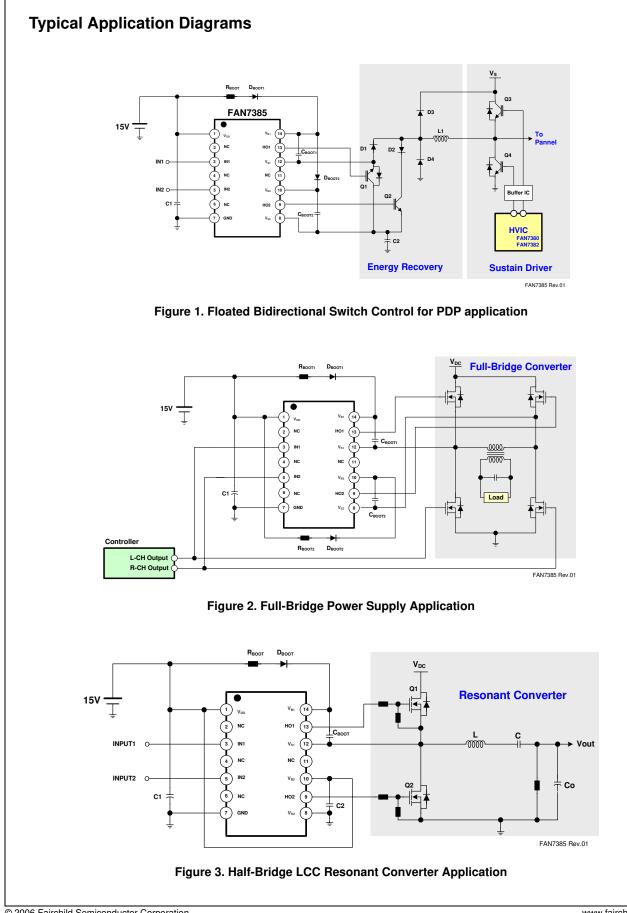
### Note:

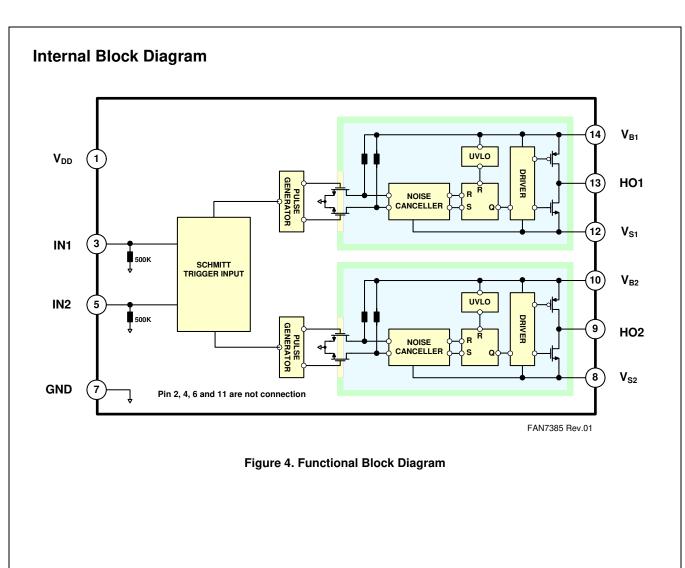
1. These devices passed wave soldering test by JESD22A-111.



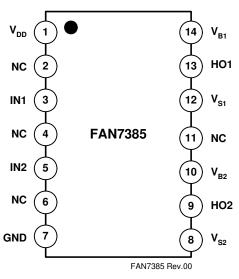


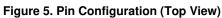






### **Pin Configuration**





### **Pin Definitions**

Pin #	Name	Description	
1	V <sub>DD</sub>	Power supply	
2	NC	Not connection	
3	IN1	Channel 1 control input	
4	NC	Not connection	
5	IN2	Channel 2 control input	
6	NC	Not connection	
7	GND	Ground	
8	V <sub>S2</sub>	Channel 2 floating supply return	
9	HO2	Channel 2 output	
10	V <sub>B2</sub>	Channel 2 floating supply	
11	NC	Not connection	
12	V <sub>S1</sub>	Channel 1 floating supply return	
13	HO1	Channel 1 output	
14	V <sub>B1</sub>	Channel 1 floating supply	

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A=25^{\circ}C$ , unless otherwise specified.

Symbol	Parameter	Min.	Max.	Unit
V <sub>S</sub>	High-side offset voltage V <sub>S1</sub> ,V <sub>S2</sub>	V <sub>B</sub> -25	V <sub>B</sub> +0.3	V
VB	High-side floating supply voltage $V_{B1}$ , $V_{B2}$	-0.3	625	V
V <sub>HO</sub>	High-side floating output voltage H <sub>O1</sub> , H <sub>O2</sub>	V <sub>S</sub> -0.3	V <sub>B</sub> +0.3	V
V <sub>DD</sub>	Low-side and logic-fixed supply voltage	-0.3	25	V
V <sub>IN</sub>	Logic input voltage (IN1, IN2)	-0.3	V <sub>DD</sub> +0.3	V
GND	Logic ground	V <sub>DD</sub> -25	V <sub>DD</sub> +0.3	V
dV <sub>S</sub> /dt	Allowable offset voltage slew rate		50	V/ns
P <sub>D</sub> <sup>(2)(3)(4)</sup>	Power dissipation		1.0	W
$\theta_{JA}$	Thermal resistance, junction-to-ambient		110	°C/W
TJ	Junction temperature		150	°C
Τ <sub>S</sub>	Storage temperature		150	°C

### Notes:

- 2. Mounted on 76.2 x 114.3 x 1.6mm PCB (FR-4 glass epoxy material).
- 3. Refer to the following standards:

JESD51-2: Integral circuits thermal test method environmental conditions - natural convection JESD51-3: Low effective thermal conductivity test board for leaded surface mount packages

4. Do not exceed P<sub>D</sub> under any circumstances.

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Condition	Min.	Max.	Unit
V <sub>B</sub>	High-side floating supply voltage		V <sub>S</sub> +10	V <sub>S</sub> +20	V
V <sub>S</sub>	High-side floating supply offset voltage 6		6-V <sub>DD</sub>	600	V
V <sub>DD</sub>	Supply voltage		10	20	V
V <sub>HO</sub>	High-side (HO1, HO2) output voltage		V <sub>S</sub>	VB	V
V <sub>IN</sub>	Logic input voltage (IN1, IN2)		GND	V <sub>DD</sub>	V
T <sub>A</sub>	Ambient temperature		-40	125	°C

### **Electrical Characteristics**

 $V_{BIAS}$  ( $V_{DD}$ ,  $V_{BS1}$ ,  $V_{BS2}$ ) = 15.0V,  $T_A$  = 25°C, unless otherwise specified. The  $V_{IN}$  and  $I_{IN}$  parameters are referenced to GND. The  $V_O$  and  $I_O$  parameters are referenced to  $V_{S1}$  and  $V_{S2}$  and are applicable to the respective outputs HO1 and HO2.

Symbol	Characteristics	Condition	Min.	Тур.	Max.	Unit
SUPPLY (	CURRENT SECTION			<b></b>	1	
I <sub>QDD</sub>	Quiescent V <sub>DD</sub> supply current	V <sub>IN1</sub> =V <sub>IN2</sub> =0V or 5V		28	50	μA
I <sub>PDD</sub>	Operating V <sub>DD</sub> supply current	f <sub>IN1</sub> =f <sub>IN2</sub> =10kHz, rms value		35	70	μA
BOOTSTR	RAPPED POWER SUPPLY SECTION					
$V_{BSUV+}$	V <sub>BS1</sub> and V <sub>BS2</sub> supply under-voltage positive going threshold	V <sub>BS1</sub> =V <sub>BS2</sub> =Sweep	8.2	9.1	10.2	V
V <sub>BSUV-</sub>	V <sub>BS1</sub> and V <sub>BS2</sub> supply under-voltage negative going threshold	V <sub>BS1</sub> =V <sub>BS2</sub> =Sweep	7.6	8.5	9.6	V
V <sub>BSHYS</sub>	V <sub>BS1</sub> and V <sub>BS2</sub> supply under-voltage lockout hysteresis	V <sub>BS1</sub> =V <sub>BS2</sub> =Sweep		0.6		V
I <sub>LK</sub>	Offset supply leakage current	V <sub>B</sub> =V <sub>S</sub> =600V			10	μA
I <sub>QBS1,2</sub>	Quiescent V <sub>BS1</sub> and V <sub>BS2</sub> supply current	V <sub>IN1</sub> =0V or 5V		50	85	μA
I <sub>PBS1,2</sub>	Operating $V_{BS1}$ and $V_{BS2}$ supply current	f <sub>IN1</sub> =10kHz, rms value		220	300	μA
GATE DR	IVER OUTPUT SECTION			•		
V <sub>OH</sub>	High-level output voltage, VBIAS-VO	I <sub>O</sub> =0mA (No Load)			30	mV
V <sub>OL</sub>	Low-level output voltage, VO	I <sub>O</sub> =0mA (No Load)			30	mV
I <sub>O+</sub>	Output HIGH short-circuit pulse current	$V_{O}=0V$ , $V_{IN}=5V$ with PW<10µs	250	350		mA
I <sub>O-</sub>	Output LOW short-circuit pulsed current	$V_{O}$ =15V, $V_{IN}$ =0V with PW<10µs	500	650		mA
V <sub>S</sub>	Allowable negative $\rm V_S$ pin voltage for IN signal propagation to $\rm H_O$			-9.8	-7.0	V
LOGIC IN	PUT SECTION (IN1 AND IN2)					
V <sub>IH</sub>	Logic "1" input voltage		2.5			V
V <sub>IL</sub>	Logic "0" input voltage				1.3	V
I <sub>IN+</sub>	Logic "1" input bias current	V <sub>IN</sub> =5V		10	20	μA
I <sub>IN-</sub>	Logic "0" input bias current	V <sub>IN</sub> =0V			2.0	μA
R <sub>IN</sub>	Input pull-down resistance		400	500	600	KΩ

### **Dynamic Electrical Characteristics**

 $T_{A}=25^{\circ}C, V_{BIAS} (V_{DD}, V_{BS1}, V_{BS2}) = 15.0V, V_{S1} = V_{S2} = GND, C_{Load} = 1000 pF \text{ unless otherwise specified.}$ 

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
t <sub>on</sub>	Turn-on propagation delay	V <sub>S</sub> =0V		110	180	ns
t <sub>off</sub>	Turn-off propagation delay	V <sub>S</sub> =0V or 600V <sup>(5)</sup>		110	180	ns
t <sub>r</sub>	Turn-on rise time			50	90	ns
t <sub>f</sub>	Turn-off fall time			30	70	ns
MT	Delay matching, Channel 1 & 2 turn- on/off			0		ns

### Notes:

5. This parameter guaranteed by design.

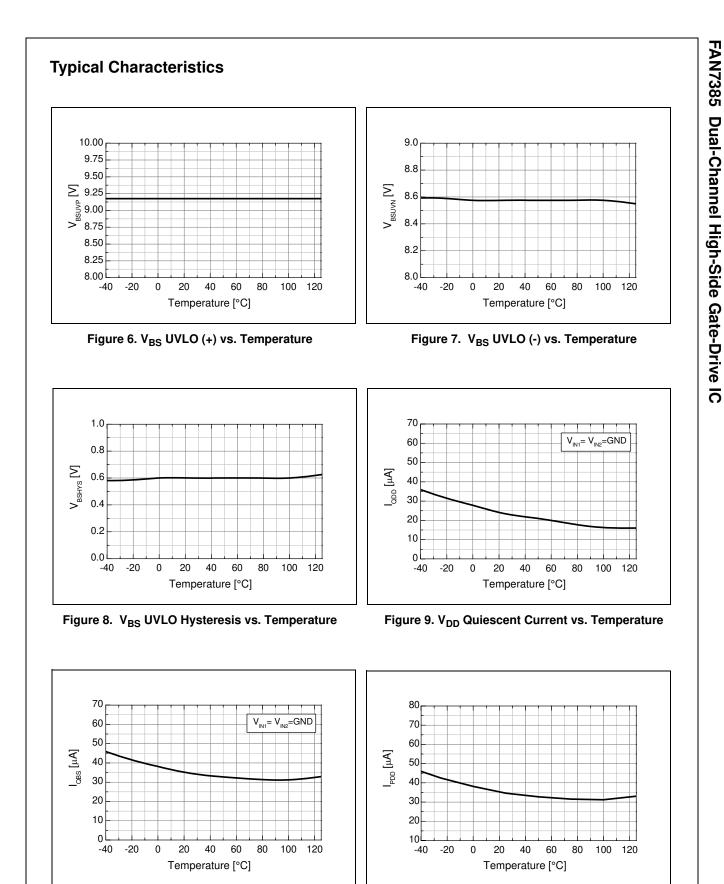




Figure 11.  $V_{DD}$  Operating Current vs. Temperature

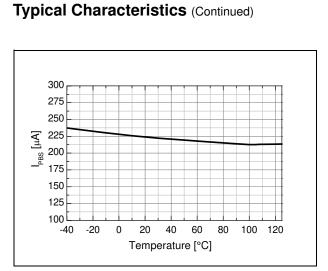


Figure 12. V<sub>BS</sub> Operating Current vs. Temperature

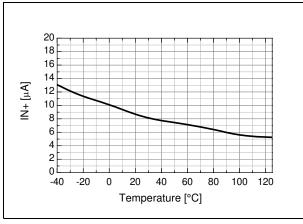


Figure 13. Logic High Input Current vs. Temperature

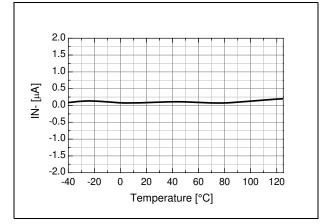


Figure 14. Logic Low Input Current vs. Temperature

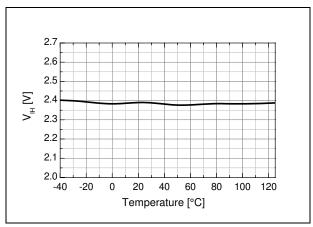


Figure 15. Logic Input High Voltage vs. Temperature

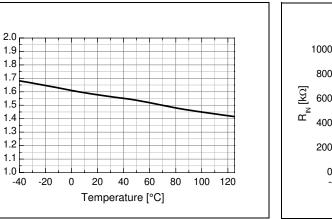
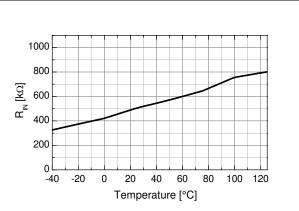


Figure 16. Logic Input Low Voltage vs. Temperature

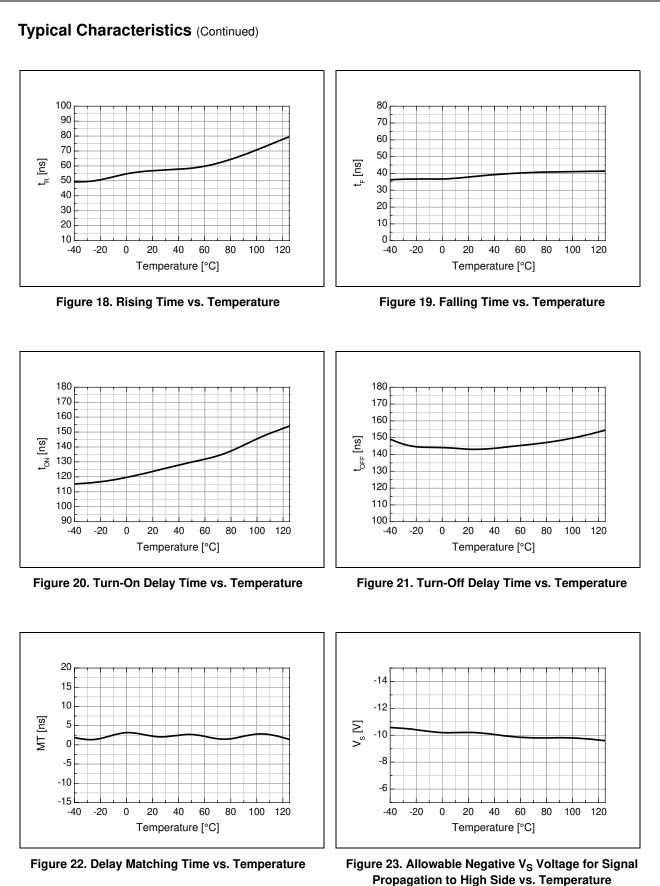


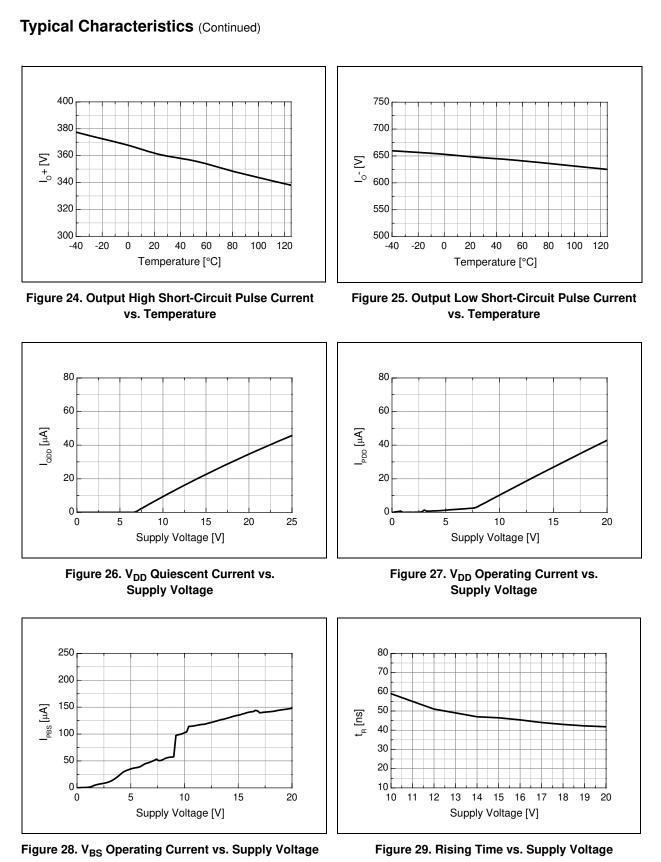


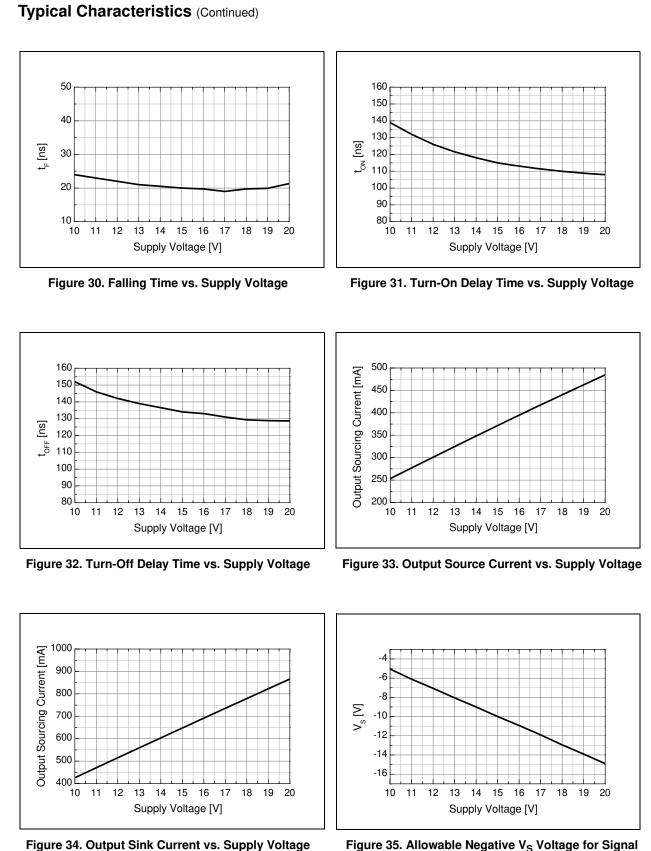
FAN7385 Dual-Channel High-Side Gate-Drive IC

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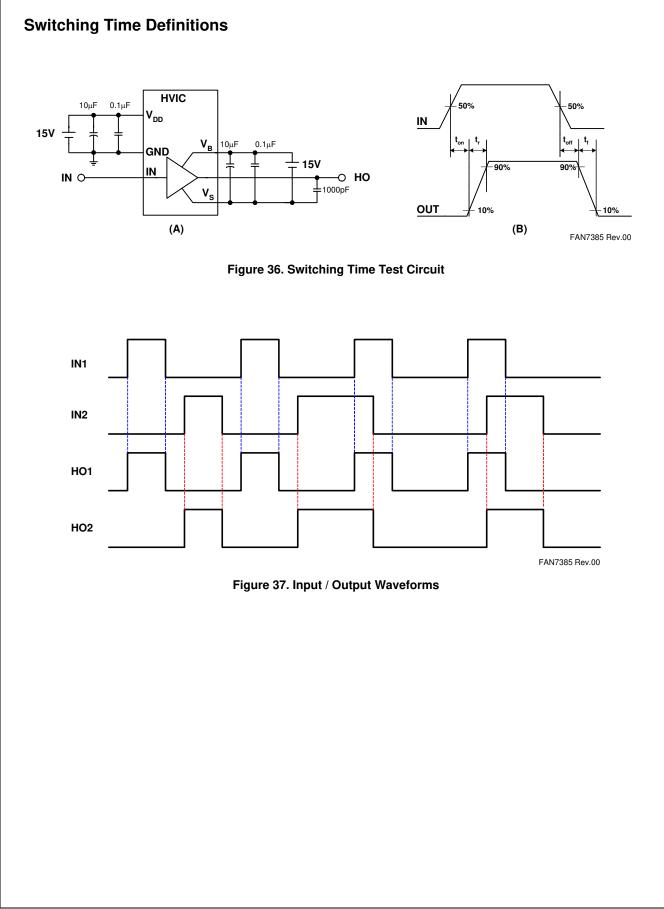
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FAN7385 Dual-Channel High-Side Gate-Drive IC



### **Typical Application Information**

### 1. Under-Voltage Lockout (UVLO)

The FAN7385 has an under-voltage lockout (UVLO) protection circuit to prevent malfunction when V<sub>BS1</sub> and V<sub>BS2</sub> are lower than the specified threshold voltage. The UVLO circuit monitors the bootstrap capacitor voltages (V<sub>BS1</sub>, V<sub>BS2</sub>) independently.

### 2. Layout Consideration

For optimum performance, considerations must be given during printed circuit board (PCB) layout.

### 2.1 Supply Capacitors

If the output stages are able to quickly turn on a switching device with a high current value, the supply capacitors must be placed as close as possible to the device pins (V<sub>DD</sub> and GND for the ground-tied supply, V<sub>B</sub> and V<sub>S</sub> for the floating supply) to minimize parasitic inductance and resistance.

### 2.2 Gate Drive Loop

Current loops behave like antennae, able to receive and transmit noise. To reduce the noise coupling/emission and improve the power switch turn-on and off performances, gate drive loops must be reduced as much as possible.

### 2.3 Ground Plane

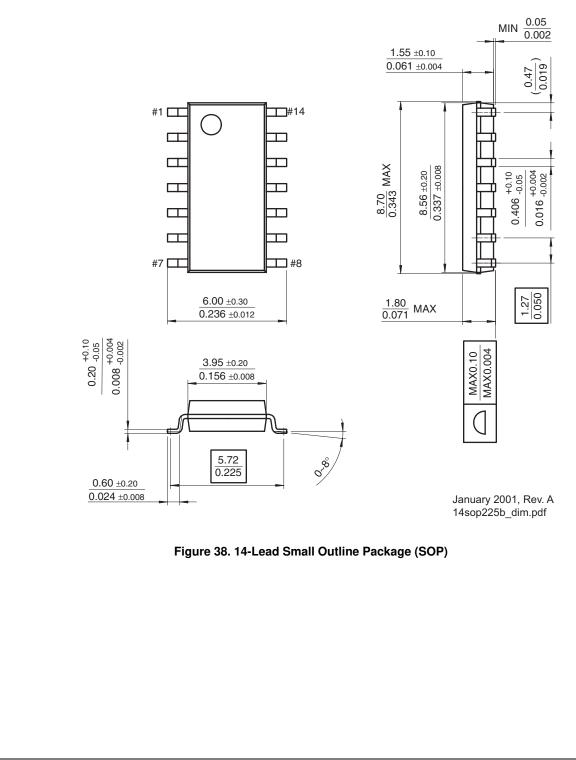
To minimize noise coupling, avoid placing the ground plane under or near the high-voltage floating side.

# FAN7385 Dual-Channel High-Side Gate-Drive IC

### Package Dimensions

### 14-SOP

Dimensions are in millimeters unless otherwise noted.





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